THERMAL RESISTANCE (TA = 25°C)

PARAMETER	SYMBOL	RATINGS	UNIT
Thermal Resistance from Junction to Ambient Note	Rth _{j-a}	80	°C/W

Note Mounted on 34.2 cm² \times 0.8 mm (t) glass epoxy PWB

RECOMMENDED OPERATING RANGE (TA = 25°C)

PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT
Collector to Emitter Voltage	VCE	-	3.6	4.5	V
Collector Current	lc	-	400	500	mA
Input Power ^{Note}	Pin	-	12	17	dBm

Note Input power under conditions of V_{CE} ≤ 4.5 V, f = 460 MHz

ELECTRICAL CHARACHTERISTICS (TA = 25°C)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
DC Characteristics						
Collector Cut-off Current	Ісво	$V_{CB} = 5 \text{ V}, \text{ I}_{E} = 0 \text{ mA}$	-	_	1	μΑ
Emitter Cut-off Current	Іево	V _{ЕВ} = 0.5 V, Ic = 0 mA	-	-	1	μA
DC Current Gain	hFE Note 1	Vce = 3 V, lc = 100 mA	80	120	180	-
RF Characteristics						
Gain Bandwidth Product	fт	Vce = 3.6 V, lc = 100 mA, f = 460 MHz	_	10	_	GHz
Insertion Power Gain	S _{21e} 2	Vce = 3.6 V, lc = 100 mA, f = 460 MHz	-	19	-	dB
Maximum Stable Gain	MSG Note 2	Vce = 3.6 V, lc = 100 mA, f = 460 MHz	-	23	-	dB
Lincor goin (1)	GL	Vce = 3.6 V, Ic (set) = 30 mA (RF OFF),	16	19	-	dB
Linear gain (1)	GL	$f = 460 \text{ MHz}, P_{in} = 0 \text{ dBm}$				
Lincar gain (2)	GL	$V_{CE} = 3.6 \text{ V}, \text{ Ic }_{(set)} = 30 \text{ mA } (\text{RF OFF}),$	-	16	-	dB
Linear gain (2)	GL	f = 900 MHz, P _{in} = 0 dBm				
Output Power (1)	Po	Vce = 3.6 V, Ic (set) = 30 mA (RF OFF),	27	29	-	dBm
	FU	f = 460 MHz, P _{in} = 15 dBm				
Output Power (2)	Po	$V_{CE} = 3.6 \text{ V}, \text{ Ic }_{(set)} = 30 \text{ mA} (\text{RF OFF}),$	-	29	-	dBm
	FU	f = 900 MHz, P _{in} = 20 dBm				
Collector Efficiency (1)	20.	Vce = 3.6 V, Ic (set) = 30 mA (RF OFF),	-	60	-	%
Collector Efficiency (1)	ης	f = 460 MHz, P _{in} = 15 dBm				
Collector Efficiency (2)		Vce = 3.6 V, Ic (set) = 30 mA (RF OFF),	-	60	-	%
Collector Efficiency (2)	ης	f = 900 MHz, P _{in} = 20 dBm				

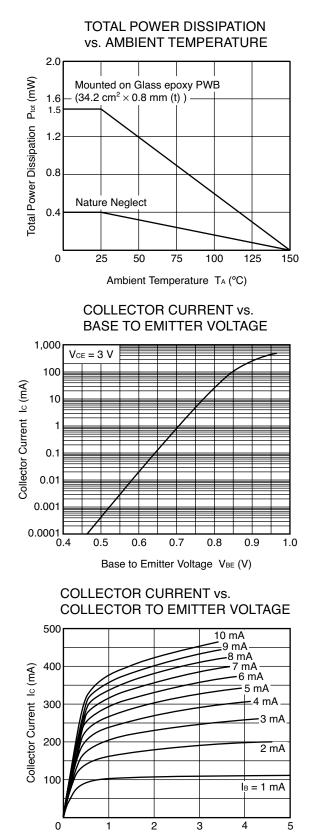
Notes 1. Pulse measurement: PW \leq 350 $\mu s,$ Duty Cycle \leq 2%

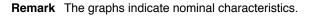
2. MSG =
$$\left| \frac{S_{21}}{S_{12}} \right|$$

hfe CLASSIFICATION

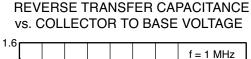
RANK	FB
Marking	SN
hfe Value	80 to 180

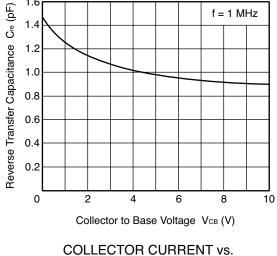
TYPICAL CHARACHTERISTICS (TA = +25°C, unless otherwise specified)



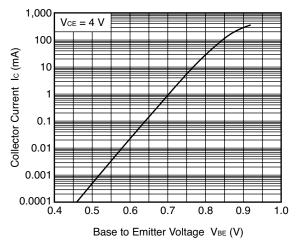


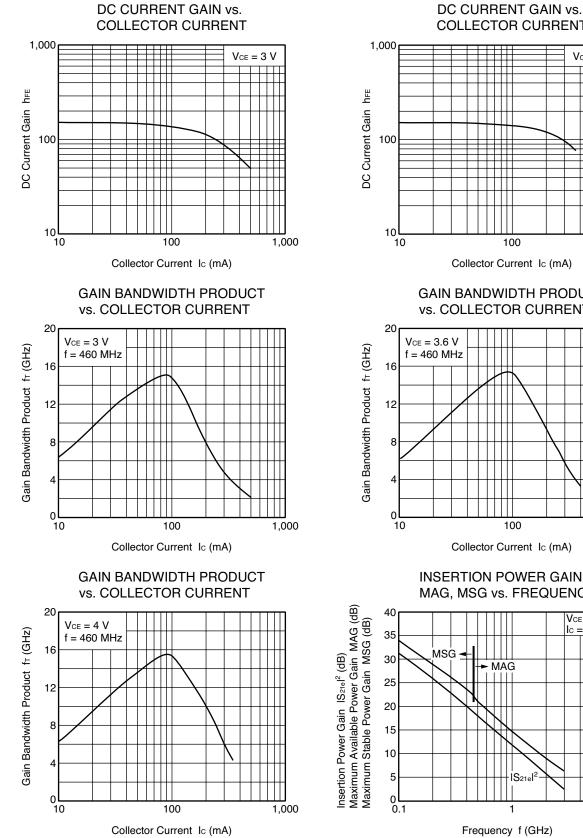
Collector to Emitter Voltage VCE (V)



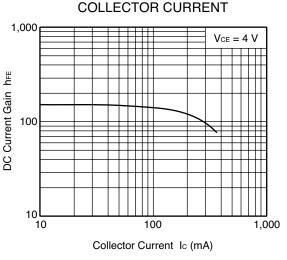


BASE TO EMITTER VOLTAGE

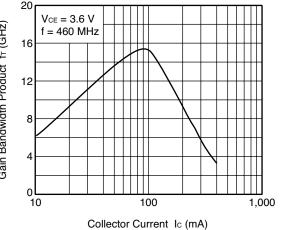




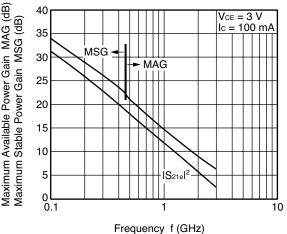
Remark The graphs indicate nominal characteristics.

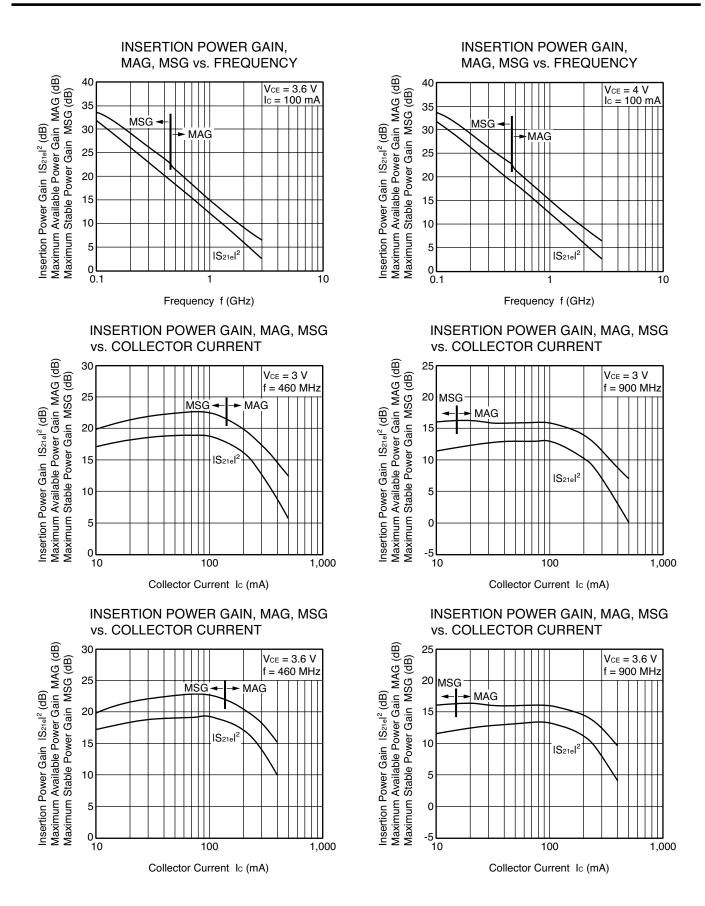


GAIN BANDWIDTH PRODUCT vs. COLLECTOR CURRENT

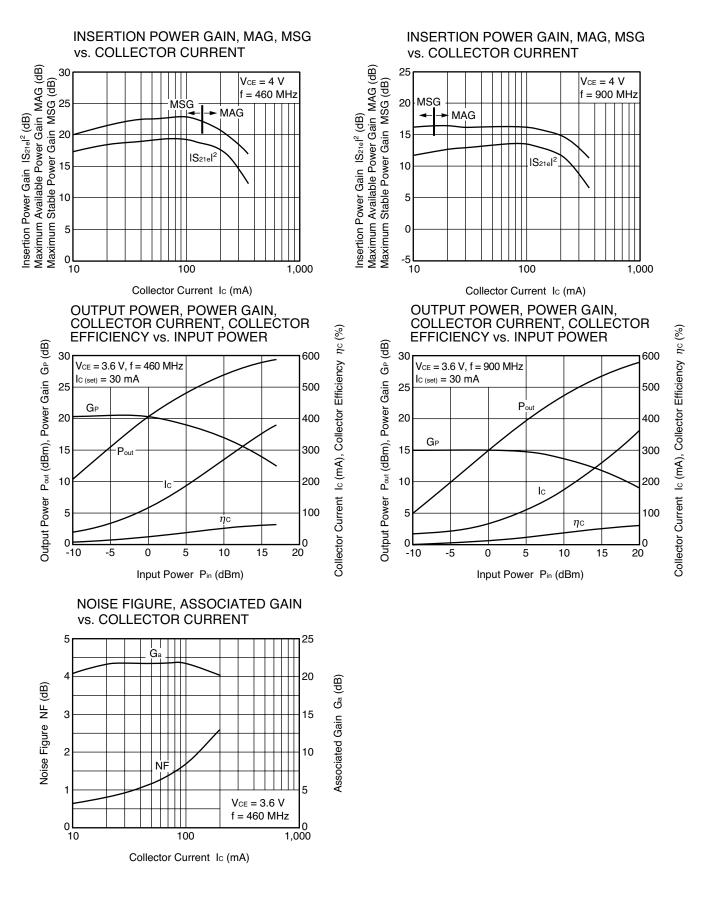


INSERTION POWER GAIN, MAG, MSG vs. FREQUENCY



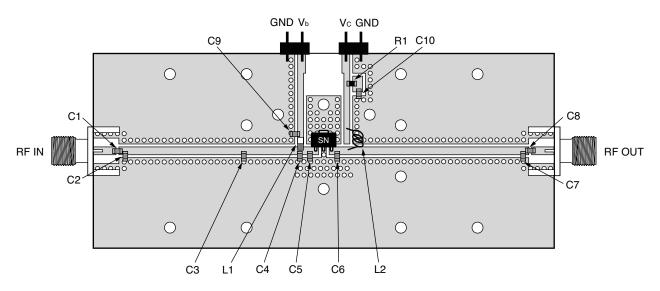


Remark The graphs indicate nominal characteristics.



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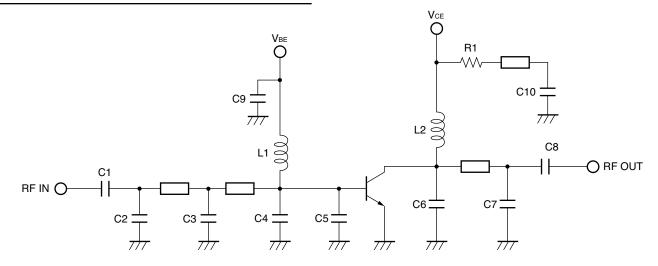
PA EVALUATION BOARD (f = 460 MHz)



Notes

- 1. 38×90 mm, t = 0.8 mm double sided copper clad glass epoxy PWB.
- 2. Back side: GND pattern
- 3. Solder gold plated on pattern
- 4. O: Through holes

PA EVALUATION CIRCUIT (f = 460 MHz)

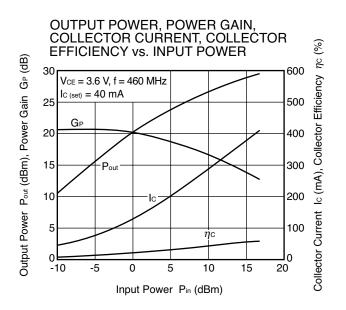


The application circuits and their parameters are for reference only and are not intended for use in actual design-ins.

COMPONENT LIST

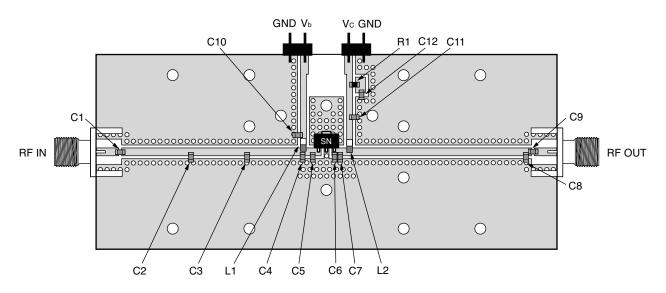
	VALUE	MAKER
C1	30 pF	Murata
C2	6 pF	Murata
C3, C4	7 pF	Murata
C5	3 pF	Murata
C6	0.5 pF	Murata
C7	5 pF	Murata
C8	10 pF	Murata
C9, C10	100 nF	Murata
L1	100 nH	Toko
L2	3 nH	Toko
R1	30 Ω	SSM

PA EVALUATION CIRCUIT TYPICAL CHARACTERISTICS



Remark The graphs indicate nominal characteristics.

DISTORTION EVALUATION BOARD (f = 460 MHz)

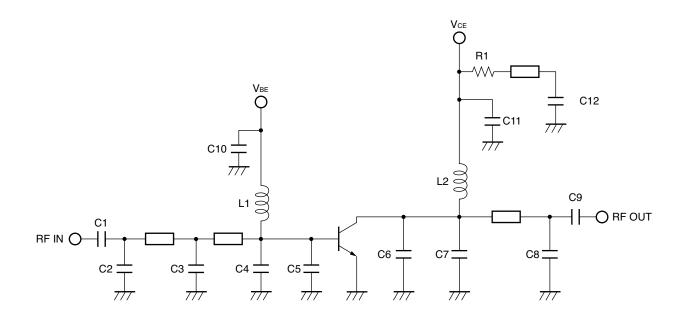


Notes

1. 38×90 mm, t = 0.8 mm, double sided copper clad glass epoxy PWB.

- 2. Back side: GND pattern
- 3. Solder gold plated on pattern
- 4. •O: Through holes

DISTORTION EVALUATION CIRCUIT (f = 460 MHz)

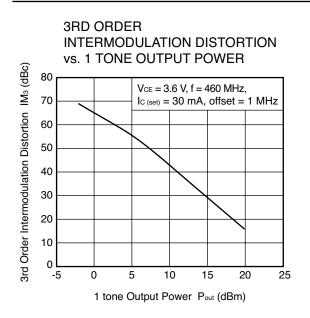


The application circuits and their parameters are for reference only and are not intended for use in actual design-ins.

COMPONENT LIST

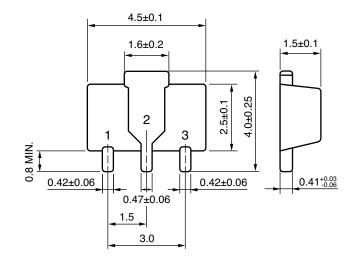
	VALUE	MAKER
C1	47 pF	Murata
C2	12 pF	Murata
C3, C4	7 pF	Murata
C5	3 pF	Murata
C6	6 pF	Murata
C7	0.5 pF	Murata
C8	5 pF	Murata
C9	51 pF	Murata
C10, C12	100 nF	Murata
C11	1 μF	Murata
L1	100 nH	Toko
L2	15 nH	Toko
R1	30 Ω	SSM

DISTORTION EVALUATION CIRCUIT TYPICAL CHARACTERISTICS



Remark The graphs indicate nominal characteristics.

3-PIN POWER MINIMOLD (34 PACKAGE) (UNIT:mm)



PIN CONNECTIONS

- 1. Collector
- 2. Emitter
- 3. Base

Life Support Applications

These NEC products are not intended for use in life support devices, appliances, or systems where the malfunction of these products can reasonably be expected to result in personal injury. The customers of CEL using or selling these products for use in such applications do so at their own risk and agree to fully indemnify CEL for all damages resulting from such improper use or sale.

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03/07/2005



Subject: Compliance with EU Directives

CEL certifies, to its knowledge, that semiconductor and laser products detailed below are compliant with the requirements of European Union (EU) Directive 2002/95/EC Restriction on Use of Hazardous Substances in electrical and electronic equipment (RoHS) and the requirements of EU Directive 2003/11/EC Restriction on Penta and Octa BDE.

CEL Pb-free products have the same base part number with a suffix added. The suffix –A indicates that the device is Pb-free. The –AZ suffix is used to designate devices containing Pb which are exempted from the requirement of RoHS directive (*). In all cases the devices have Pb-free terminals. All devices with these suffixes meet the requirements of the RoHS directive.

This status is based on CEL's understanding of the EU Directives and knowledge of the materials that go into its products as of the date of disclosure of this information.

Restricted Substance per RoHS	Concentration Limit per RoHS (values are not yet fixed)	Concentration contained in CEL devices		
Lead (Pb)	< 1000 PPM	-A Not Detected	-AZ (*)	
Mercury	< 1000 PPM	Not Detected		
Cadmium	< 100 PPM	Not Detected		
Hexavalent Chromium	avalent Chromium < 1000 PPM		Not Detected	
РВВ	< 1000 PPM	Not Detected		
PBDE < 1000 PPM		Not Detected		

If you should have any additional questions regarding our devices and compliance to environmental standards, please do not hesitate to contact your local representative.

In no event shall CEL's liability arising out of such information exceed the total purchase price of the CEL part(s) at issue sold by CEL to customer on an annual basis.

See CEL Terms and Conditions for additional clarification of warranties and liability.

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